NSN 5962-01-332-5751

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-332-5751

Overall Width:
Between 0.745 inches and 1.040 inches
De de Leveth

Body Length: 0.540 inches

Body Width:

Between 0.245 inches and 0.300 inches

Body Height:

Between 0.045 inches and 0.100 inches

Maximum Power Dissipation Rating:

0.6 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Bipolar and monolithic and programmable and w/clock and 3-state output and w/enable

Inclosure Material:

Ceramic

Inclosure Configuration:

Flat pack

Output Logic Form:

Bipolar metal-oxide semiconductor

Input Circuit Pattern:

16 input

Case Outline Source And Designator:

F-9 mil-m-38510

Current Rating Per Characteristic:

12.00 milliamperes average forward current averaged over a full 60-hz cycle not applicable

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Time Rating Per Chacteristic:

20.00 nanoseconds propagation delay time, low to high level output and 20.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Pal

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

20 flat leads

Shelf Life:

N/a

NSN 5962-01-332-5751

Memory Microcircuit - Page 2 of 2



			ure:	

--

Demilitarization:

No

Fiig:

A458a0